

U.S. UTILITY Patent Ap	plication
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APPLICATION NO.	CONT/PRIOR	CLASS	SUBCLASS	ART UNIT	EXAMINER
09/660484	F	438	12.	2812	Atmosphalano

Yasuo Tanaka

Method of manufacturing semiconductor device

ISSUING CLASSIFICATION ORIGINAL CROSS REFERENCE(S) **SUBCLASS** CLASS SUBCLASS (ONE SUBCLASS PER BLOCK) INTERNATIONAL CLASSIFICATION Continued on Issue Slip Inside File Jacket

TERMINAL DISCLAIMER	DRAWINGS			CLAIMS ALLOWED		
	Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims	Print Claim for O.G	
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